

XJNG2102

200V 1A Half Bridge Driver

General description:

The XJNG2102 is a high voltage, high speed power MOSFET drivers with dependent high- and low-side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3 V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET in the high-side configuration which operates up to 200 V.

Features:

- Floating channel designed for bootstrap operation
- Fully operational to +200 V
- Tolerant to negative transient voltage, dV/dt immune
- Gate drive supply range from 6 V to 18 V
- 3.3 V input logic compatible
- Typically output Source/Sink current capability 1A/1A



- Power MOSFET driver
- Half / Full-Bridge Power Converters
- Any Complementary Drive Converters

Package Marking and Ordering Information

0 0	0				
Device	Order code	Order code Device Package Device Mar			
XJNG2102	XJNG2102	SOIC8	XJNG2102		

Typical Application Circuit





XJNG2102

Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units
VB	High side floating supply	-0.3	225	V
Vs	High side floating supply return	V _B – 25	V _B + 0.3	V
V _{HO}	High side gate drive output	V _S -0.3	V _B + 0.3	V
Vcc	Low side and main power supply	-0.3	25	V
V _{LO}	Low side gate drive output	-0.3	V _{CC} + 0.3	V
V _{IN}	V _{IN} Logic input of HIN & LIN		V _{CC} + 0.3	V
dVs/dt	dVs/dt Allowable offset supply voltage transient		50	V/ns
PD	P _D Package Power Dissipation @ TA ≤25°C (SOIC-8)		0.625	W
Rth _{JA}	Rth _{JA} Thermal Resistance Junction to Ambient (SOIC-8)		200	°C /W
TJ	T _J Junction Temperature		150	°C
Ts	T _s Storage Temperature		150	°C
ΤL	T _L Lead Temperature (Soldering, 10 seconds)		300	°C
	HBM Model	1500		V
ESD	CDM Model	500		V

Recommended Operating Conditions

For proper operation the device should be used within the recommended conditions. The V_s offset rating is tested with all supplies biased at a 15 V differential

Symbol	Definition	Min.	Max.	Units
VB	High side floating supply	V _S + 6	V _S + 20	V
Vs	High side floating supply return	-6	200	V
V _{HO}	High side gate drive output	Vs	Vв	V
Vcc	Low side and main power supply	6	20	V
V _{LO}	Low side gate drive output	0	V _{CC}	V
V _{IN}	Logic input of HIN & LIN	0	V _{CC}	V
T _A	Ambient temperature	-40	125	°C

Dynamic Electrical Characteristics

VBIAS (VCC, VBS) = 15V, C_L = 1000 pF and T_A = 25°C unless otherwise specified

Symbol	ymbol Definition		Тур.	Max.	Units
ton	ton Turn on propagation delay		150	250	ns
t _{OFF} Turn off propagation delay			140	250	ns
MT Delay matching time (t _{ON} , t _{OFF})				50	ns
DT Dead time			200		ns
t _R Turn on rising time			50	100	ns
t _F	Turn off falling time		40	100	ns





Static Electrical Characteristics

VBIAS (VCC, VBS) = 15V, CL = 1000 pF and TA = 25°C unless otherwise specified.

Symbol	Definition	Min.	Тур.	Max.	Units
VIH	High level input threshold voltage	2.5	_	_	V
VIL	Low level input threshold voltage	_	_	0.8	V
V _{OH}	High level output voltage drop, V_{BIAS} - V_{O}	—	—	0.2	V
V _{OL}	Low level output voltage drop, $V_{\rm O}$	—	—	0.1	V
I _{LK}	High-side floating supply leakage current	—	—	1	μA
I _{QBS}	I _{QBS} Quiescent V _{BS} supply current		40	120	μA
I _{QCC}	Quiescent V _{CC} supply current	—	160	280	μA
I _{IN+}	Logic "1" input bias current (HIN "1" & LIN "1")	—	10	20	μA
I _{IN-}	Logic "0" input bias current (HIN "0" & LIN "0")	—	—	1	μA
V _{CCUV+}	VCC supply undervoltage positive going threshold	_	5.5	_	V
V _{CCUV} -	VCC supply undervoltage negative going threshold	—	5.0	_	V
I _{O+}	Output High short circuit pulsed current	_	1	_	А
I ₀₋	Output low short circuit pulsed current	_	1		А

Function Block Diagram







XJNG2102

Pin Configuration

		_	Pin No.	Pin Name	Pin Function
	VD		1	Vcc	Low side and main power supply
	VB	L.	2	HIN	Logic input for high side gate driver output (HO)
2 HIN	но	7	3	LIN	Logic input for low side gate driver output (LO)
XJNG2102			4	СОМ	Ground
3 LIN	vs	6	5	LO	Low side gate drive output, out of phase with LIN
			6	Vs	High side floating supply return or bootstrap return
	LU	μ	7	НО	High side gate drive output, in phase with HIN
		-	8	VB	High side floating supply
					5 5 H 7

Function Timing Diagram







Package Information

OIC-8 Package Dimensions								
Size Symbol	MIN(mm)	TYP(mm)	MAX(mm)	Size Symbol	MIN(mm)	TYP(mm)	MAX(mm)	
А	-	-	1.75	D	4.70	4.90	5.10	
A1	0.10	-	0.225	Е	5.80	6.00	6.20	
A2	1.30	1.40	1.50	E1	3.70	3.90	4.10	
A3	0.60	0.65	0.70	е	1.27BSC			
b	0.39	-	0.48	h	0.25	-	0.50	
b1	0.38	0.41	0.43	L	0.50	-	0.80	
с	0.21	-	0.26	L1	1.05BSC			
c1	0.19	0.20	0.21	θ	0	-	8°	

SOIC-8 Package Outlines





Pb Free Product

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